DATASHEET

ITR8307/L24/F43

Features

- Thin
- Fast response time
- High sensitivity
- Pb free
- High analytic
- Compact

Description

The **ITR8307/L24/F43** consist of an infrared emitting diode and an NPN silicon phototransistor, encased side-by-side on converging optical axis in a black
thermoplastic housing The phototransistor receives radiation from the IR only .This is the normal situation. But when an object is in between, phototransistor could not receive the radiation.

Applications

- Various microcomputer control equipment
- Floppy disk driver
- Cassette type recorder
- Camera
- VCR

Device Selection Guide

Device No.	Chip Material	LENS COLOR
IR	GaAs	Water Clear
PT	Silicon	Water Clear

Absolute Maximum Ratings (Ta=25℃)

Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25℃ Free Air Temperature	Pd	75	mW
	Reverse Voltage	V_R	6	V
	Forward Current	I_F	50	mA
	Peak Forward Current (*1) Pulse width ≦100 μs, Duty cycle=1%	I_{FP}	1	A
Output	Collector Power Dissipation	P_C	100	mW
	Collector Current	I_C	20	mA
	Collector-Emitter Voltage	B V_{CEO}	35	V
	Emitter-Collector Voltage	B V_{ECO}	6	V
Operating Temperature		Topr	-25~+85	℃
Storage Temperature		Tstg	-30~+90	℃
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		Tsol	260	℃

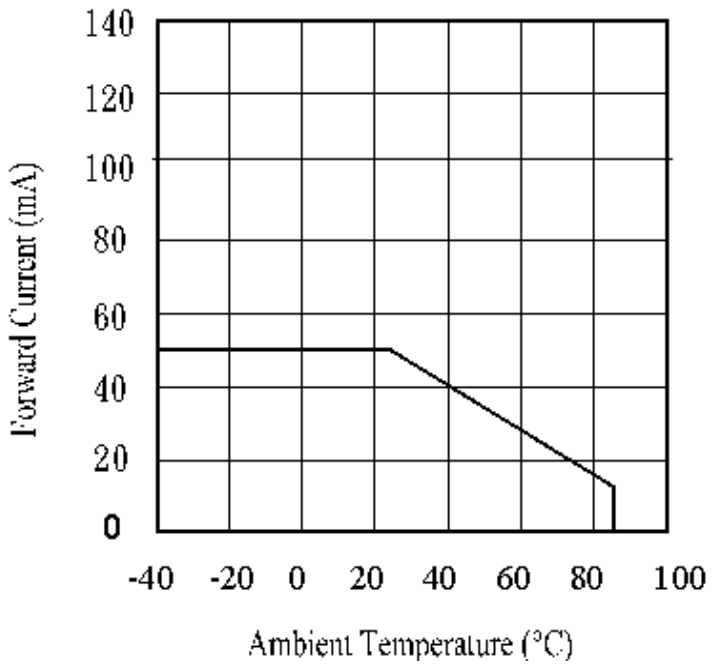
(＊1) tw=100 μsec., T=10 msec. (＊2) t=5 Sec

Electro-Optical Characteristics (Ta=25℃) 业务技术咨询：TEL/微信:13422876592

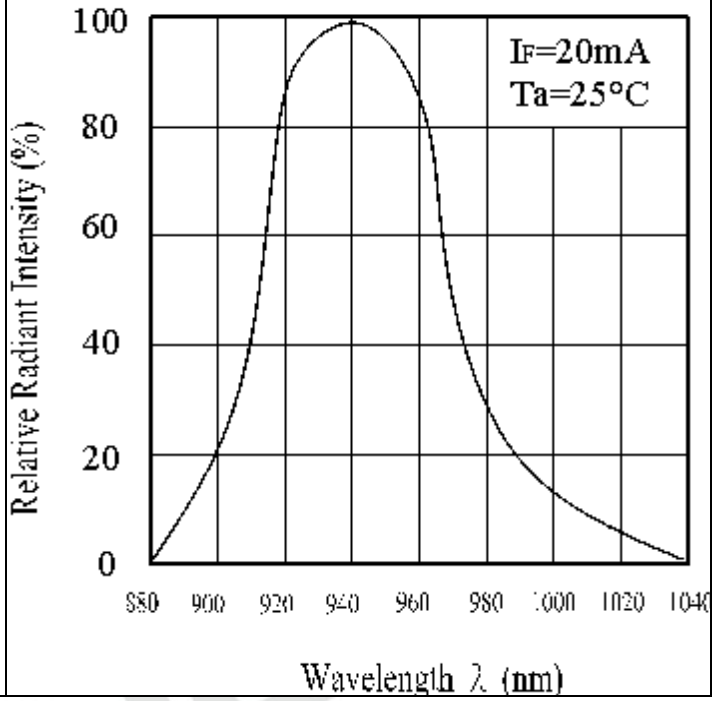
Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input	Forward Voltage	V_F	---	1.2	1.4	V	I_F=20mA
	Reverse Current	I_R	---	---	10	μ A	V_R=5V
	Peak Wavelength	λ_P	---	940	---	nm	I_F=20mA
Output	Dark Current	I_{CEO}	---	---	1	μA	V_{CE}=10V , Ee=1mW/cm^2
Transfer Characteristics	Collect Current	I_C(ON)	0.5	---	---	mA	V_{CE}=5V I_F=20mA
	Leakage Current	ILEAK	---	---	5	μA	V_{CE}=2V I_F=4mA
	Rise time	t_r	---	80	400	μs	V_{CE}=2V I_C=10mA R_L=100Ω d = 1mm
	Fall time	t_f	---	70	400	μs	

Typical Electrical/Optical/Characteristics Curves for IR

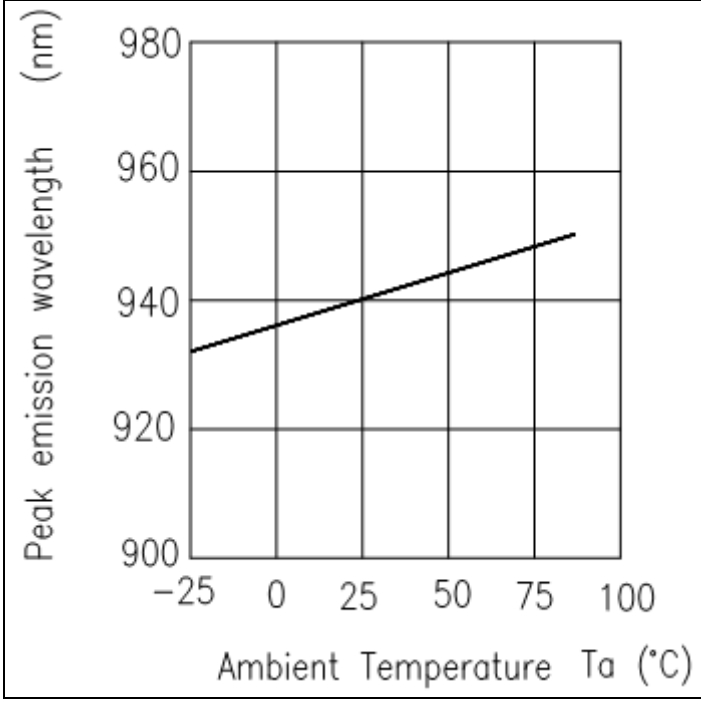
Forward Current vs. Ambient Temperature



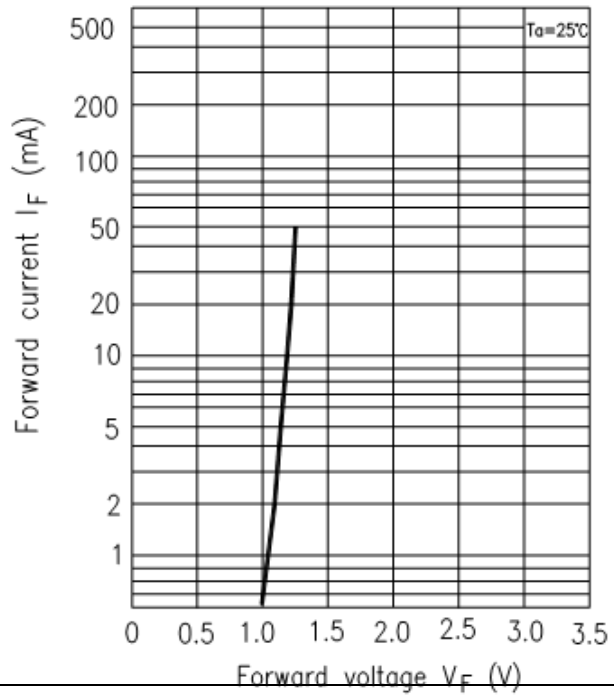
Spectral Distribution

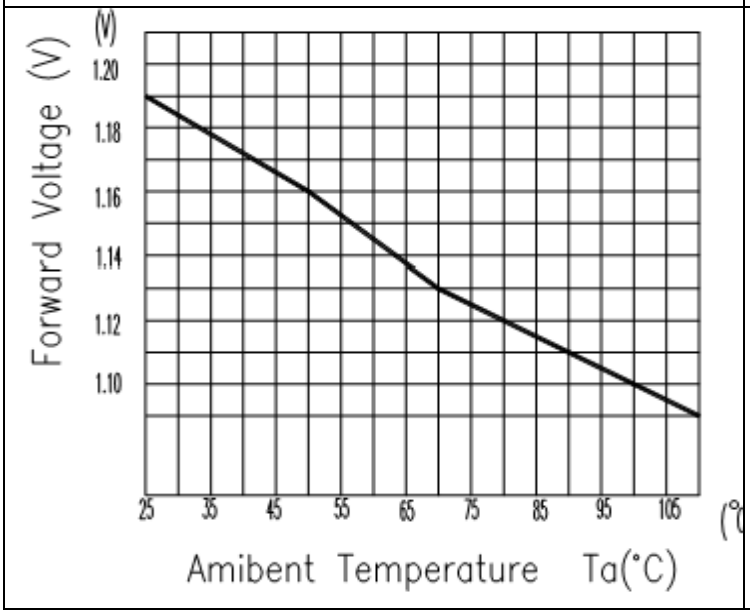
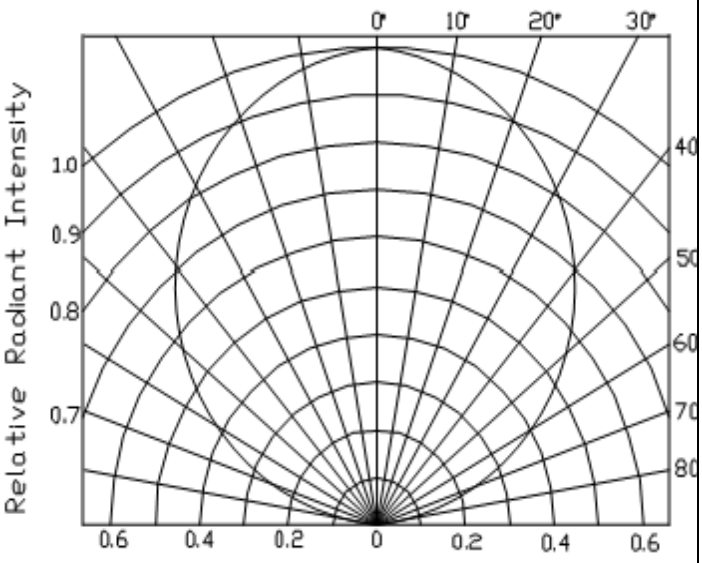


Peak Emission Wavelenght vs. Ambient Temperature

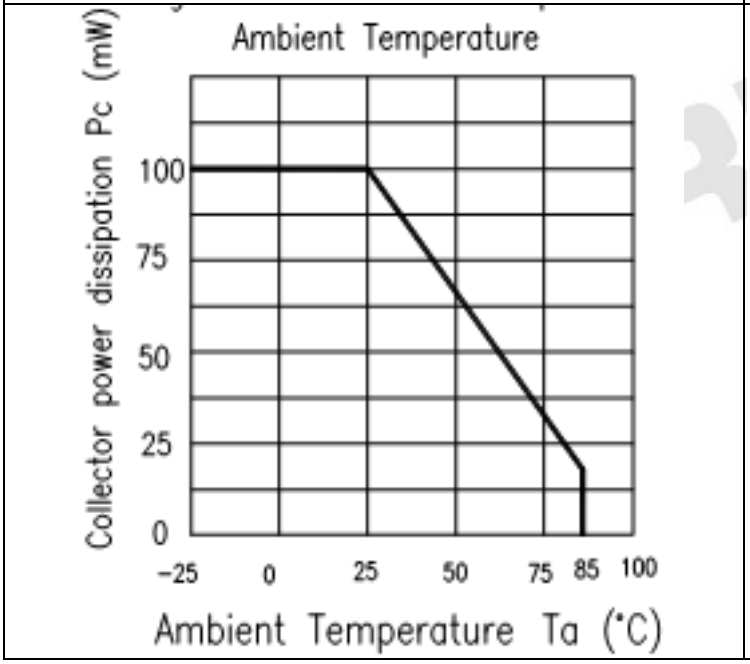
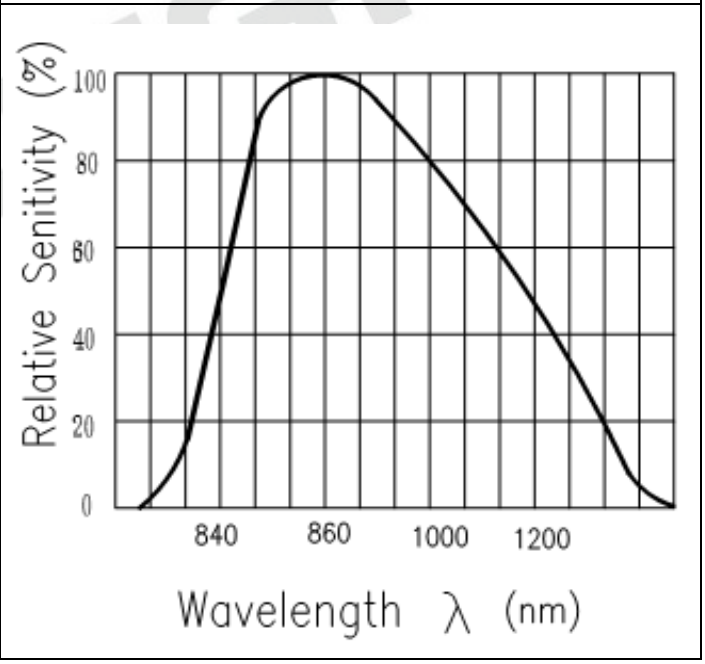


Forward Current vs. Forward Voltage

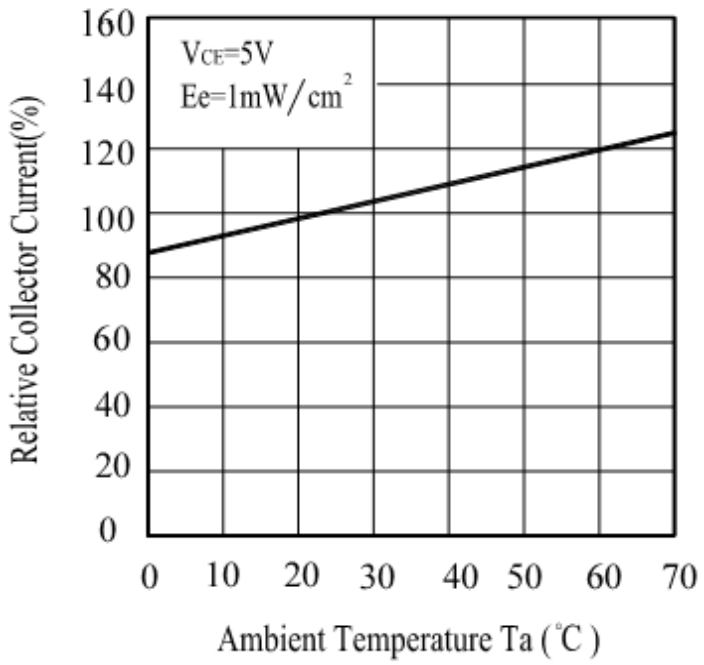


Forward Voltage vs. Ambient Temperature	Relative Radiant Intensity vs. Angular Displacement
	

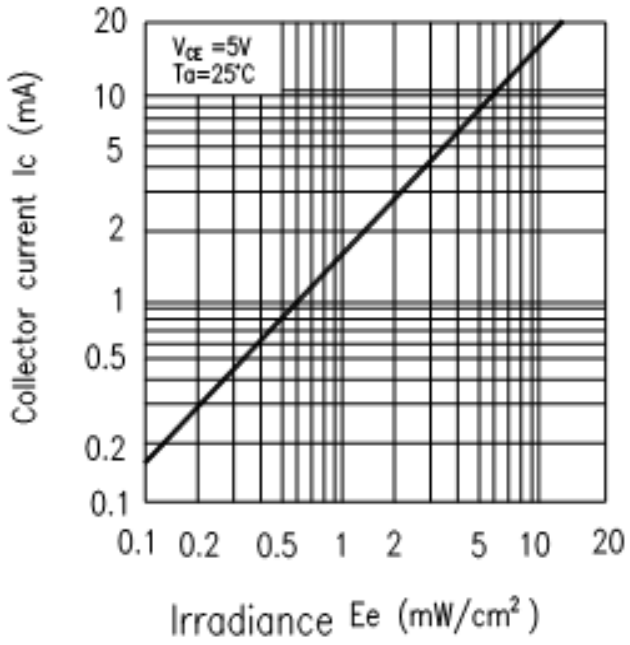
Typical Electro/Optical/Characteristics Curves for PT

Collector Power Dissipation vs. Ambient Temperature	Spectral Sensitivity
	

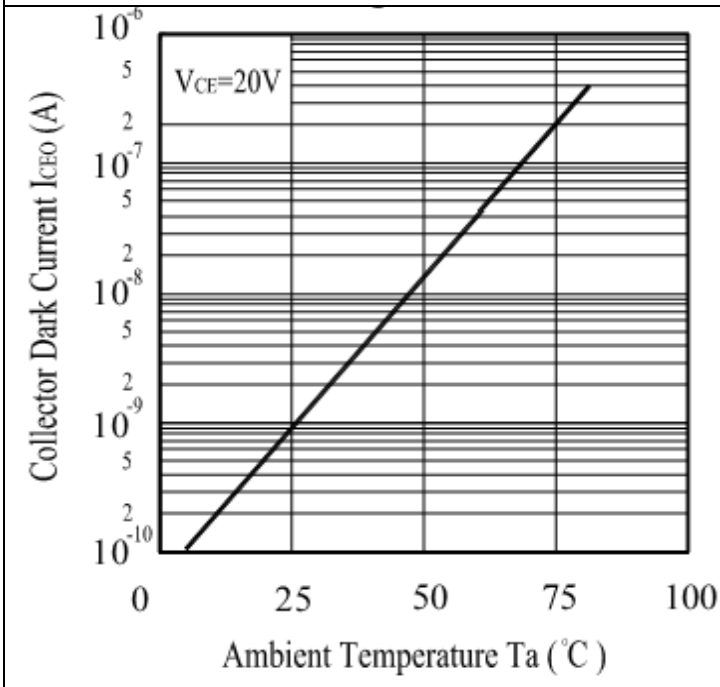
Relative Collector Current vs Ambient Temperature



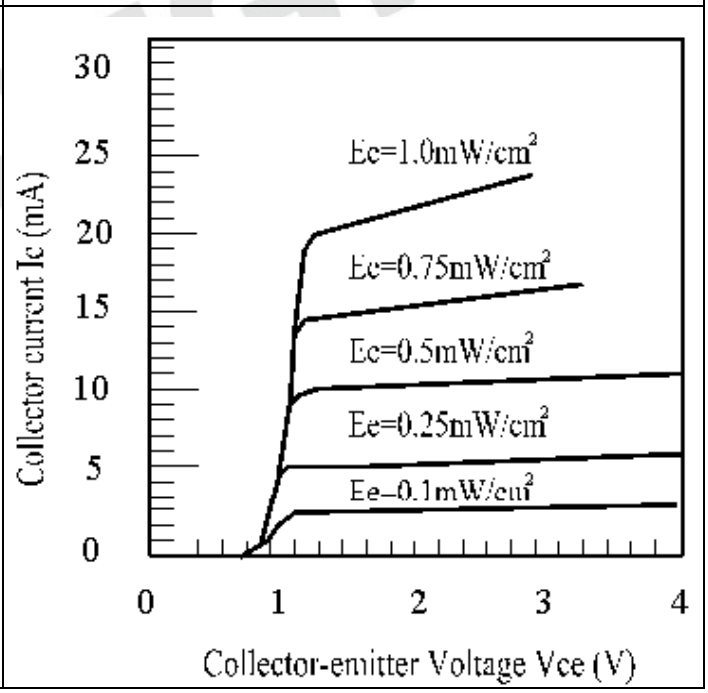
Collector Current vs. Irradiance



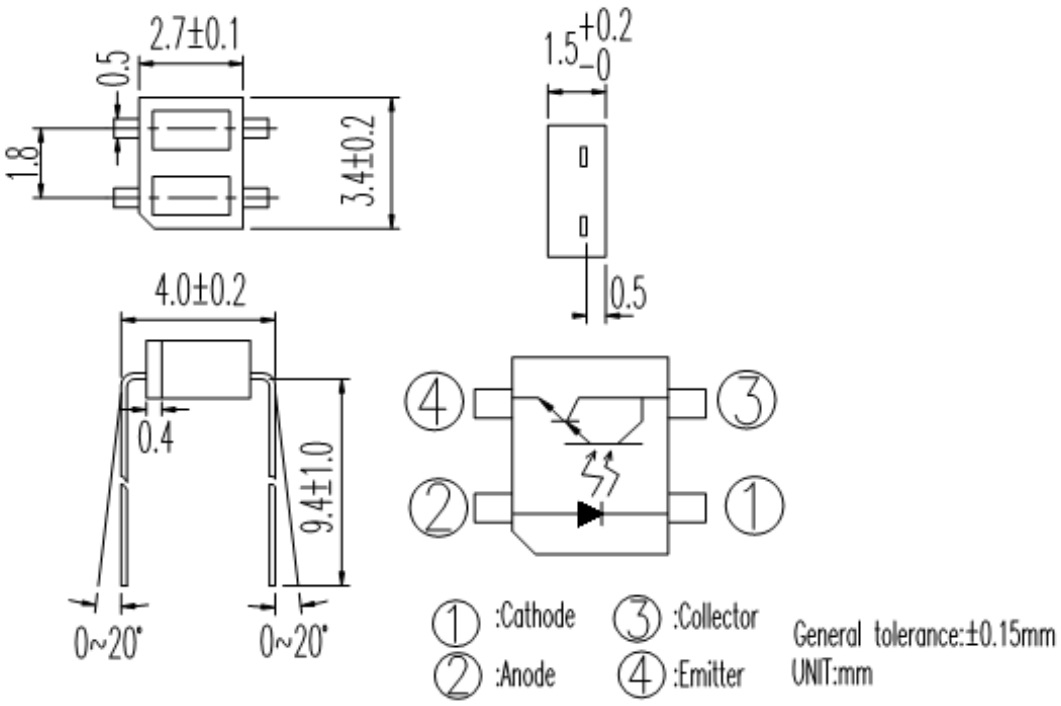
Collector Current vs. Ambient Temperatrue



Collector Current vs. Collector-emitter Voltage



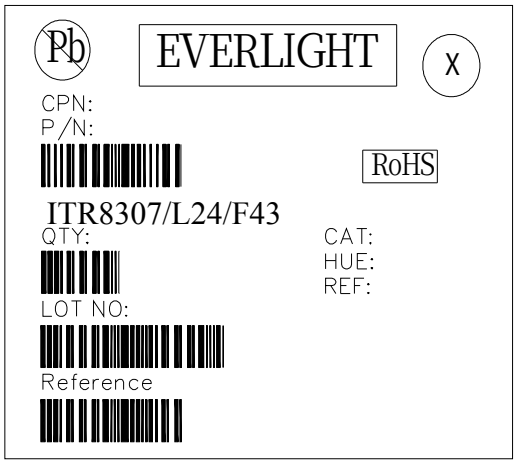
Package Dimension



Notes: 1.All dimensions are in millimeters
2.Tolerances unless dimensions ±0.25mm

Packing Quantity Specification
1. 1000pcs/1Bag
2. 1Bag/1Carton

Label Form Specification



- CPN: Customer's Product Number
- P/N: Product Number
- QTY: Packing Quantity
- CAT: Luminous Intensity Rank
- HUE: Dom. Wavelength Rank
- REF: Forward Voltage Rank
- LOT No: Lot Number
- X: Month
- Reference: Identify Label Number

Notes
1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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